NSN 5962-01-531-0948

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View Online at https://aerobasegroup.com/nsn/5962-01-531-0948

Body Length:	
0.640 inches	
Body Width:	
Between 0.300 inches and 0.420	inches
Body Height:	
Between 0.045 inches and 0.090	inches
Maximum Power Dissipation F	ating:
1.02 watts	
Operating Tempurature Range	:
-55.0/+125.0 degrees celsius	
Storage Tempurature Range:	
-65.0/+150.0 degrees celsius	
End Application:	
F-15 avionics	
Features Provided:	
Hermetically sealed and burn in	and bipolar and programmable and schottky
Inclosure Material:	
Ceramic	
Inclosure Configuration:	
Flat pack	
Output Logic Form:	
Transistor-transistor logic	
Input Circuit Pattern:	
13 input	
Terminal Surface Treatment:	
Solder	
Product Name:	
Microcircuit, digital prom 512 x 8	-bit, bipolar
Voltage Rating And Type Per (haracteristic:
7.0 volts power source	
Time Rating Per Chacteristic:	
90.00 nanoseconds propagatior	delay time, low to high level output and 90.00 nanoseconds propagation delay time, high to low level
output	
Memory Device Type:	
Prom	
Memory Capacity:	
512 word x 8 bit	
Terminal Type And Quantity:	
24 flat leads	
Shelf Life:	
N/a	
Unit Of Measure:	

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Demilitarization:

Yes - demil/mli

Fiig:

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